"High Side Chopper" IGBT SOT-227, 70 A



SOT-227

FEATURES

- Trench IGBT technology
- Higher switching frequency up to 150 kHz
- Square RBSOA
- Low $V_{CE(on)}$
- FRED Pt® hyperfast rectifier
- Fully isolated package
- Very low internal inductance (≤ 5 nH typical)
- Industry standard outline
- UL approved file E78996
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

Pb-free

RoHS COMPLIANT

BENEFITS

- Designed for increased operating efficiency in power conversion: UPS, SMPS, welding, induction heating
- Easy to assemble and parallel
- Direct mounting to heatsink
- Plug-in compatible with other SOT-227 packages
- Lower conduction losses and switching losses
- Low EMI, requires less snubbing

PRIMARY CHARACTERISTICS	
V_{CES}	600 V
I_C DC	70 A at 57 °C
$V_{CE(on)}$ typical at 70 A, 25 °C	1.79 V
I_F DC	70 A at 86 °C
Package	SOT-227
Circuit configuration	High side chopper

ABSOLUTE MAXIMUM RATINGS				
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS
Collector to emitter voltage	V_{CES}		600	V
Continuous collector current	I_C	T_C = 25 °C	81	A
		T_C = 80 °C	61	
Pulsed collector current	I_{CM}		170	
Clamped inductive load current	I_{LM}		250	
Diode continuous forward current	I_F	T_C = 25 °C	113	
		T_C = 80 °C	75	
Single pulse forward current	I_{FSM}	10 ms sine or 6 ms rectangular pulse, T_J = 25 °C	390	
Gate to emitter voltage	V_{GE}		± 20	V
Power dissipation, IGBT	P_D	T_C = 25 °C	231	W
		T_C = 80 °C	146	
Power dissipation, diode	P_D	T_C = 25 °C	330	
		T_C = 80 °C	179	
RMS isolation voltage	V_{ISOL}	Any terminal to case, t = 1 min	2500	V

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ELECTRICAL SPECIFICATIONS (T_J = 25 °C unless otherwise specified)						
PARAMETER	**SYMBOL**	**TEST CONDITIONS**	**MIN.**	**TYP.**	**MAX.**	**UNITS**
Collector to emitter breakdown voltage	$V_{BR(CES)}$	V_{GE} = 0 V, I_C = 0.4 mA	600	-	-	V
Collector to emitter voltage	$V_{CE(on)}$	V_{GE} = 15 V, I_C = 35 A	-	1.44	-	
		V_{GE} = 15 V, I_C = 70 A	-	1.79	2.26	
		V_{GE} = 15 V, I_C = 35 A, T_J = 125 °C	-	1.60	-	
		V_{GE} = 15 V, I_C = 70 A, T_J = 125 °C	-	2.02	-	
Gate threshold voltage	$V_{GE(th)}$	V_{CE} = V_{GE}, I_C = 0.6 mA	2.9	3.9	5.1	
Temperature coefficient of threshold voltage	$\Delta V_{GE(th)}/\Delta T_J$	V_{CE} = V_{GE}, I_C = 0.6 mA (25 °C to 125 °C)	-	-10.0	-	mV/°C
Collector to emitter leakage current	I_{CES}	V_{GE} = 0 V, V_{CE} = 600 V	-	0.2	100	µA
		V_{GE} = 0 V, V_{CE} = 600 V, T_J = 125 °C	-	19	-	
Diode reverse breakdown voltage	V_{BR}	I_R = 1 mA	600	-	-	V
Diode forward voltage drop	V_{FM}	I_F = 35 A, V_{GE} = 0 V	-	1.67	2.33	V
		IF = 70 A, V_{GE} = 0 V	-	1.96	-	
		IF = 35 A, V_{GE} = 0 V, T_J = 125 °C	-	1.23	-	
		IF = 70 A, V_{GE} = 0 V, T_J = 125 °C	-	1.55	-	
Diode reverse leakage current	I_{RM}	V_R = 600 V	-	0.1	50	µA
		T_J = 125 °C, V_R = 600 V	-	0.04	-	mA
Gate to emitter leakage current	I_{GES}	V_{GE} = ± 20 V	-	-	± 200	nA

SWITCHING CHARACTERISTICS (T_J = 25 °C unless otherwise specified)							
PARAMETER	**SYMBOL**	**TEST CONDITIONS**		**MIN.**	**TYP.**	**MAX.**	**UNITS**
Total gate charge (turn-on)	Q_g	I_C = 70 A, V_{CC} = 520 V, V_{GE} = 15 V		-	193	-	nC
Gate to emitter charge (turn-on)	Q_{ge}			-	29	-	
Gate to collector charge (turn-on)	Q_{gc}			-	56	-	
Turn-on switching loss	E_{on}	I_C = 35 A, V_{CC} = 300 V, V_{GE} = 15 V, R_g = 4.7 Ω, L = 500 µH, T_J = 25 °C	Energy losses include tail and diode recovery	-	0.35	-	mJ
Turn-off switching loss	E_{off}			-	0.15	-	
Total switching loss	E_{tot}			-	0.5	-	
Turn-on switching loss	E_{on}	I_C = 70 A, V_{CC} = 300 V, V_{GE} = 15 V, R_g = 4.7 Ω, L = 500 µH, T_J = 25 °C		-	0.8	-	
Turn-off switching loss	E_{off}			-	0.34	-	
Total switching loss	E_{tot}			-	1.14	-	
Turn-on switching loss	E_{on}	I_C = 35 A, V_{CC} = 300 V, V_{GE} = 15 V, R_g = 4.7 Ω, L = 500 µH, T_J = 125 °C		-	0.56	-	
Turn-off switching loss	E_{off}			-	0.25	-	
Total switching loss	E_{tot}			-	0.81	-	
Turn-on delay time	$t_{d(on)}$			-	24	-	ns
Rise time	t_r			-	9	-	
Turn-off delay time	$t_{d(off)}$			-	105	-	
Fall time	t_f			-	31	-	
Turn-on switching loss	E_{on}	I_C = 70 A, V_{CC} = 300 V, V_{GE} = 15 V, R_g = 4.7 Ω, L = 500 µH, T_J = 125 °C		-	0.95	-	mJ
Turn-off switching loss	E_{off}			-	0.53	-	
Total switching loss	E_{tot}			-	1.48	-	
Turn-on delay time	$t_{d(on)}$			-	26	-	ns
Rise time	t_r			-	23	-	
Turn-off delay time	$t_{d(off)}$			-	101	-	
Fall time	t_f			-	24	-	
Reverse bias safe operating area	RBSOA	T_J = 175 °C, I_C = 250 A, R_g = 4.7 Ω, V_{GE} = 15 V to 0 V, V_{CC} = 300 V, V_P = 600 V		Fullsquare			
Diode reverse recovery time	t_{rr}	I_F = 50 A, dI_F/dt = 200 A/µs, V_R = 200 V		-	64	-	ns
Diode peak reverse current	I_{rr}			-	4.5	-	A
Diode recovery charge	Q_{rr}			-	144	-	nC
Diode reverse recovery time	t_{rr}	I_F = 50 A, dI_F/dt = 200 A/µs, V_R = 200 V, T_J = 125 °C		-	136	-	ns
Diode peak reverse current	I_{rr}			-	12	-	A
Diode recovery charge	Q_{rr}			-	807	-	nC

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THERMAL AND MECHANICAL SPECIFICATIONS							
PARAMETER		SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS
Junction and storage temperature range		T_J, T_{Stg}		-40	-	175	°C
Junction to case	IGBT	R_{thJC}		-	-	0.65	°C/W
	Diode			-	-	0.53	
Case to heatsink		R_{thCS}	Flat, greased surface	-	0.05	-	
Weight				-	30	-	g
Mounting torque			Torque to terminal	-	-	1.1 (9.7)	Nm (lbf.in)
			Torque to heatsink	-	-	1.3 (11.5)	Nm (lbf.in)
Case style		SOT-227					

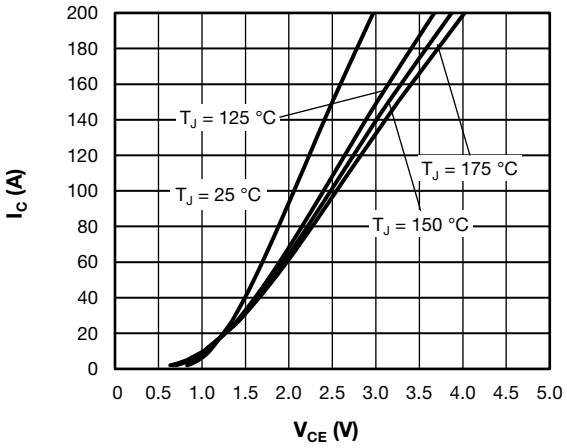


Fig. 1 - Typical Trench IGBT Output Characteristics, V_{GE} = 15 V

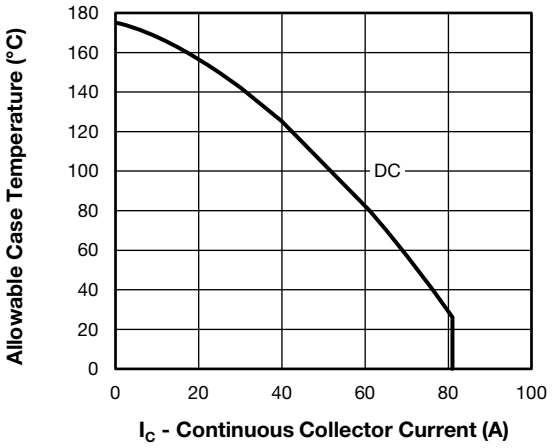


Fig. 3 - Maximum Trench IGBT Continuous Collector Current vs. Case Temperature

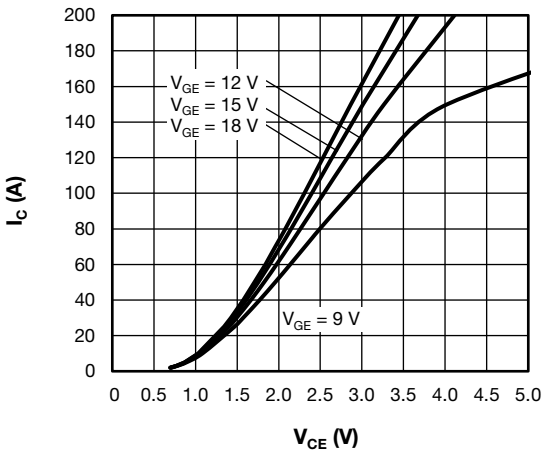


Fig. 2 - Typical Trench IGBT Output Characteristics, T_J = 125 °C

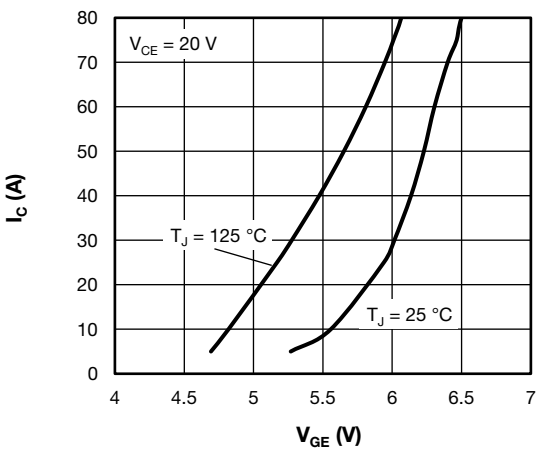


Fig. 4 - Typical Trench IGBT Transfer Characteristics

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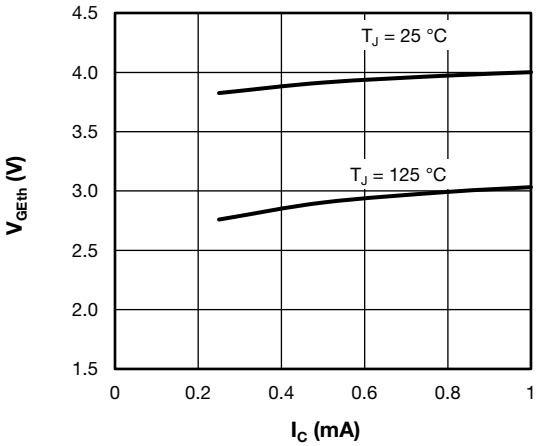


Fig. 5 - Typical Trench IGBT Gate Threshold Voltage

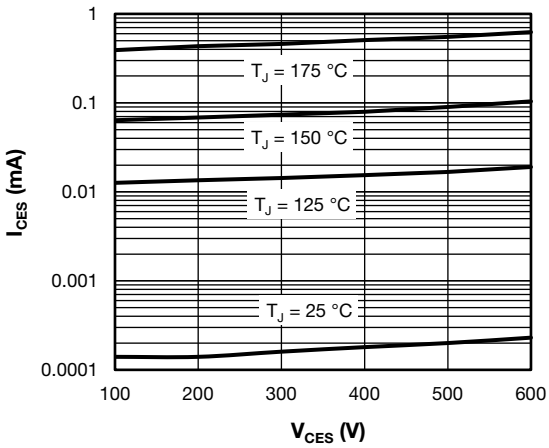


Fig. 6 - Typical Trench IGBT Zero Gate Voltage Collector Current

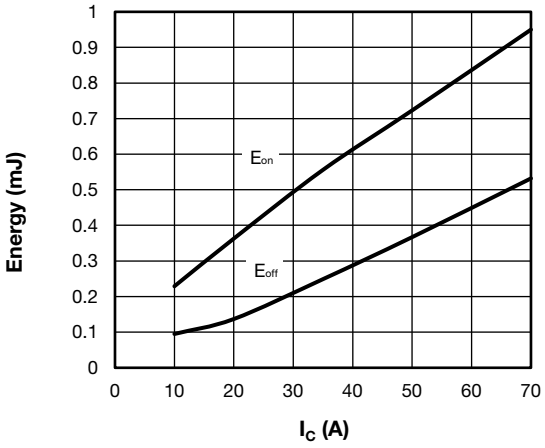


Fig. 7 - Typical Trench IGBT Energy Loss vs. I_C
(with Antiparallel Diode)
T_J = 125 °C, V_{CC} = 300 V, R_g = 4.7 Ω, V_{GE} = +15 V/-15 V, L = 500 µH

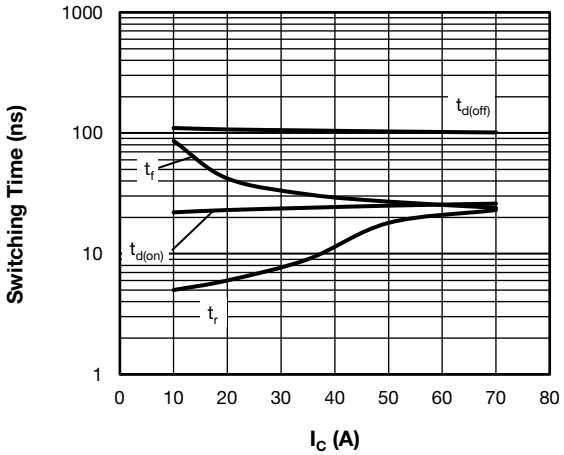


Fig. 8 - Typical Trench IGBT Switching Time vs. I_C
(with Antiparallel Diode)
T_J = 125 °C, V_{CC} = 300 V, R_g = 4.7 Ω, V_{GE} = +15 V/-15 V, L = 500 µH

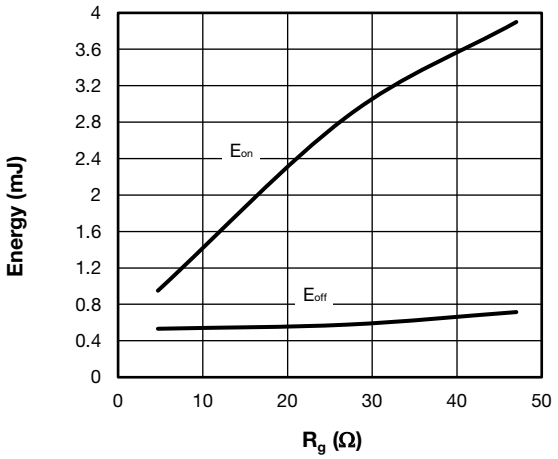


Fig. 9 - Typical Trench IGBT Energy Loss vs. R_g
(with Antiparallel Diode)
T_J = 125 °C, V_{CC} = 300 V, I_C = 70 A, V_{GE} = +15 V/-15 V, L = 500 µH

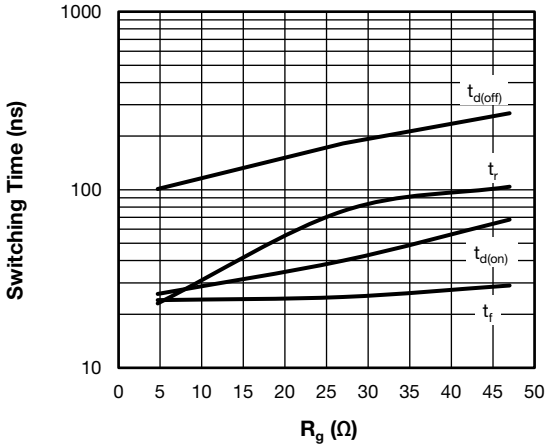


Fig. 10 - Typical Trench IGBT Switching Time vs. R_g
(with Antiparallel Diode)
T_J = 125 °C, V_{CC} = 300 V, I_C = 70 A, V_{GE} = +15 V/-15 V, L = 500 µH

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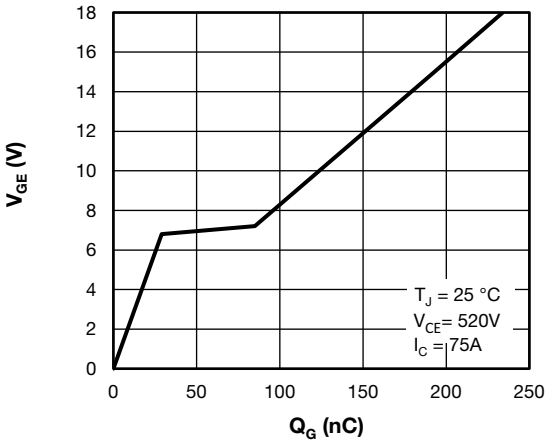


Fig. 11 - Typical Trench IGBT Gate Charge vs. Gate to Emitter Voltage

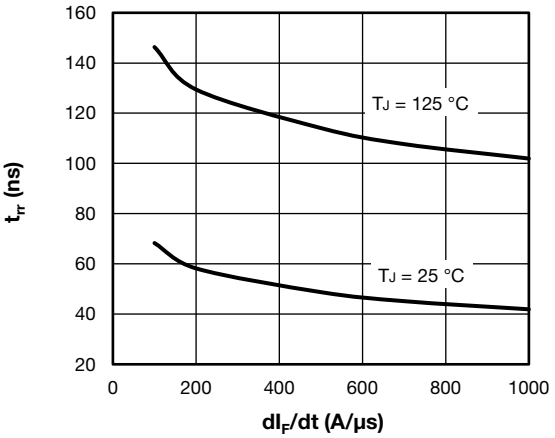


Fig. 14 - Typical Diode Reverse Recovery Time vs. dI_F/dt
I_F = 50 A, V_{CC} = 200 V

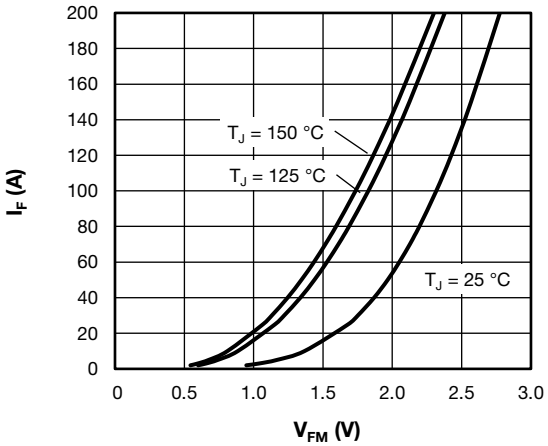


Fig. 12 - Typical Diode Forward Characteristics

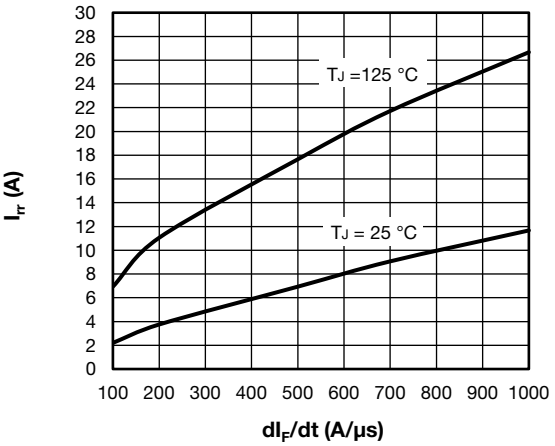


Fig. 15 - Typical Diode Reverse Recovery Current vs. dI_F/dt
I_F = 50 A, V_{CC} = 200 V

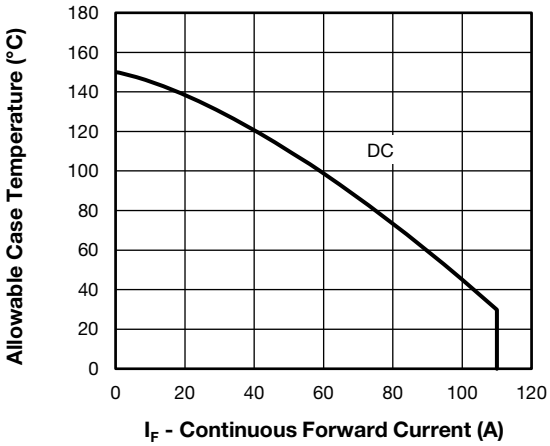


Fig. 13 - Maximum Diode Continuous Forward Current vs. Case Temperature

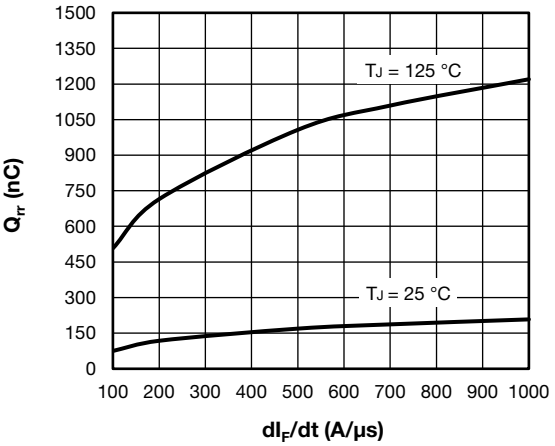


Fig. 16 - Typical Diode Reverse Recovery Charge vs. dI_F/dt
I_F = 50 A, V_{CC} = 200 V

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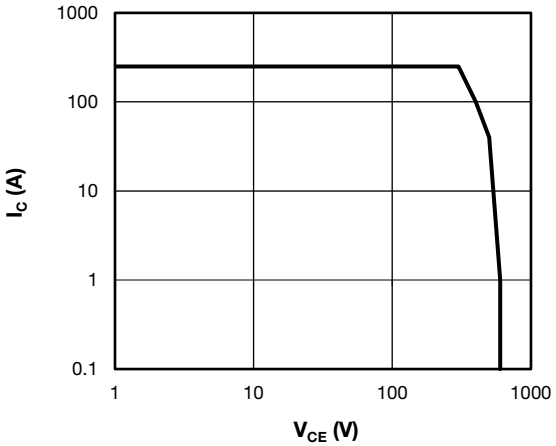


Fig. 17 - Trench IGBT Reverse BIAS SOA
T_J = 175 °C, I_C = 250 A, R_g = 4.7 Ω, V_{GE} = +15 V/0 V,
V_{CC} = 300 V, V_p = 600 V

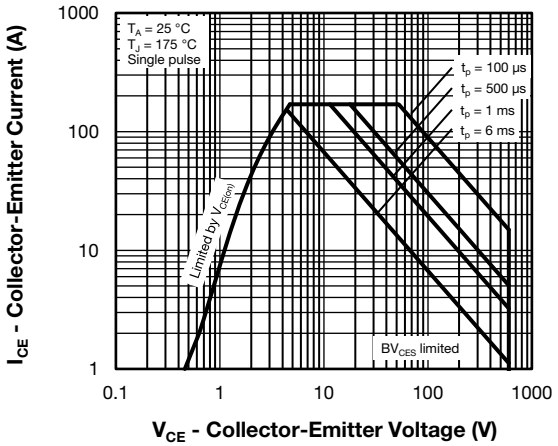


Fig. 18 - Trench IGBT Safe Operating Area

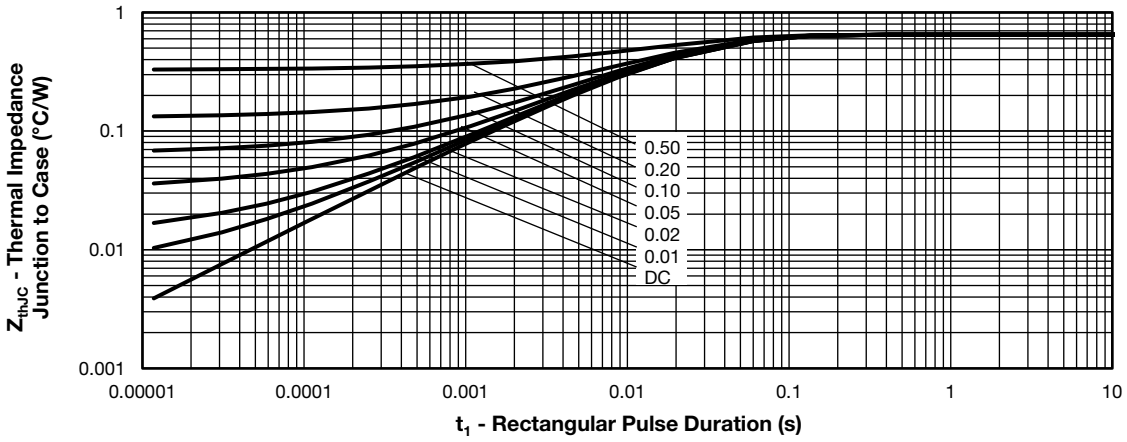


Fig. 19 - Maximum Trench IGBT Thermal Impedance Z_{thJC} Characteristics

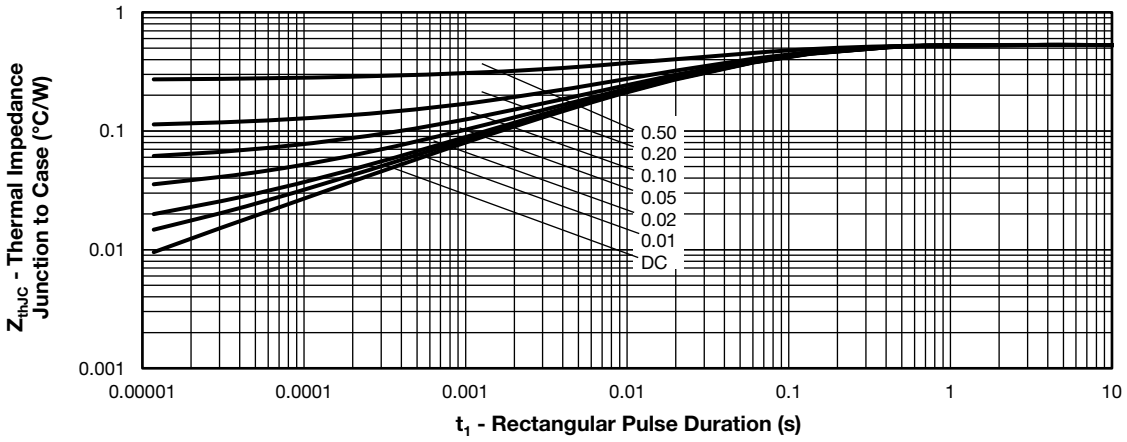


Fig. 20 - Maximum Diode Thermal Impedance Z_{thJC} Characteristics

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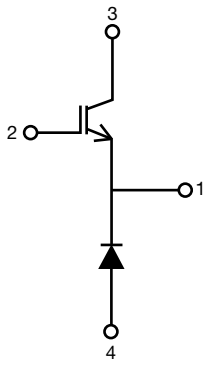
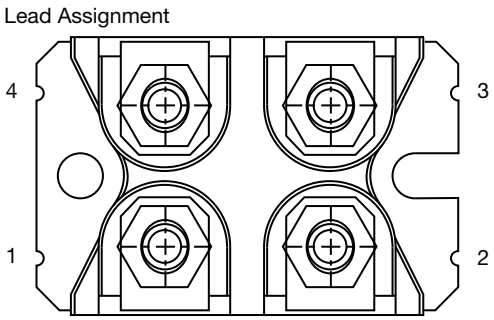
ORDERING INFORMATION TABLE

Device code

VS-	G	T	75	N	A	60	U	F
1	2	3	4	5	6	7	8	9

1 - Vishay Semiconductors product
2 - Insulated gate bipolar transistor (IGBT)
3 - T = Trench IGBT
4 - Current rating (75 = 75 A)
5 - Circuit configuration (N = high side chopper)
6 - Package indicator (A = SOT-227)
7 - Voltage rating (60 = 600 V)
8 - Speed / type (U = ultrafast IGBT)
9 - Diode (F = FRED Pt® diode)

CIRCUIT CONFIGURATION

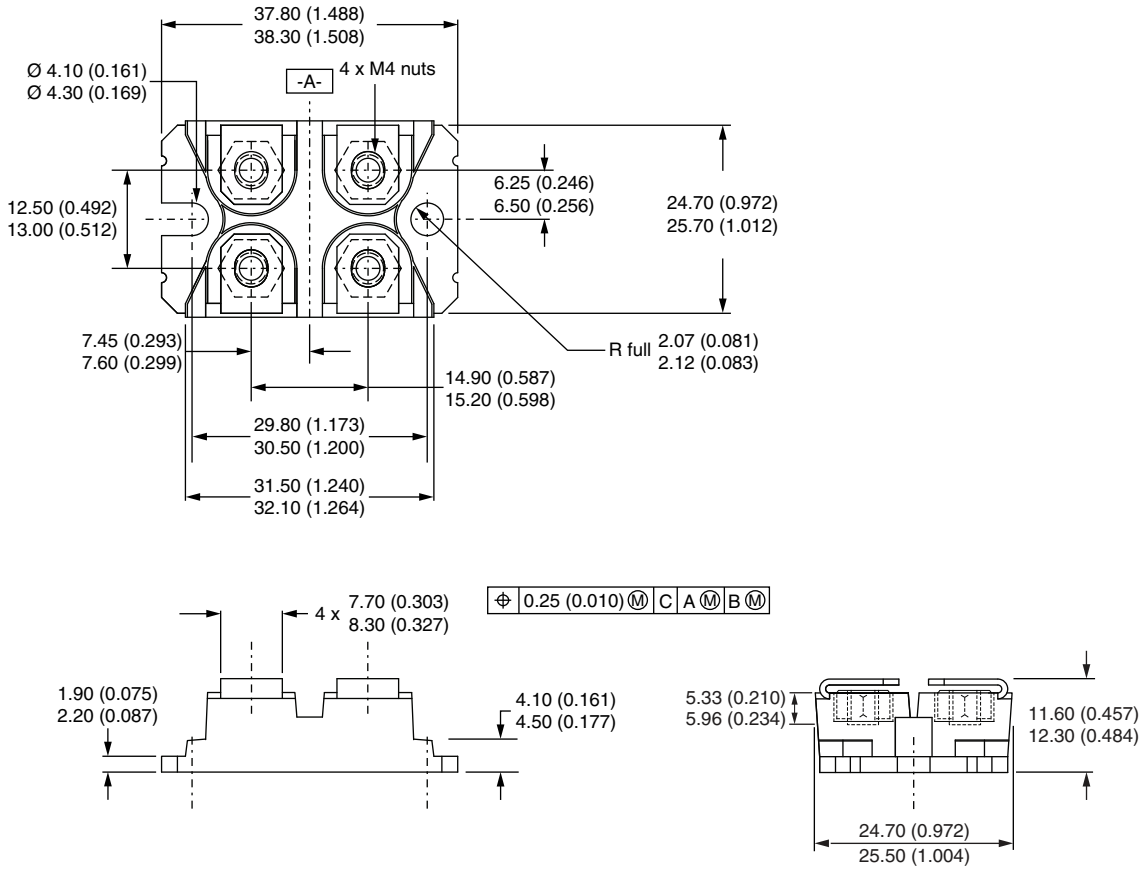
CIRCUIT	CIRCUIT CONFIGURATION CODE	CIRCUIT DRAWING	
High side chopper	N		

LINKS TO RELATED DOCUMENTS	
Dimensions	www.vishay.com/doc?95423
Packaging information	www.vishay.com/doc?95425

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SOT-227 Generation 2

DIMENSIONS in millimeters (inches)



Note

- Controlling dimension: millimeter

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